Semiconductor Device Set - Page 1 of 1



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Glas	8
Over	all Length:
0.180) inches
Term	ninal Length:
1.000) inches
Over	all Diameter:
0.074	1 inches
Inter	nal Configuration:
Junc	tion contact all semiconductor device diode
Join	t Electronic Device Engineering Council/jedec/case Outline Designation:
Do-3	5
Elec	trode Internally-electrically Connected To Case:
Colle	ctor
Inter	nal Junction Configuration:
Pn a	I semiconductor device diode
Com	ponent Function Relationship:
Matc	hed
Com	ponent Name And Quantity:
4 ser	niconductor device diode
Mou	nting Method:
Term	inal
Feat	ures Provided:
Herm	netically sealed case
Sem	iconductor Material:
Silico	on all semiconductor device diode
Volta	age Rating In Volts Per Characteristic:
200.0) reverse voltage, peak all semiconductor device diode
Curr	ent Rating Per Characteristic:
30.00) milliamperes forward current, average peak all semiconductor device diode
Term	ninal Type And Quantity:
2 uni	nsulated wire lead
Shel	f Life:
N/a	
Unit	Of Measure:
Dem	ilitarization:
No	
Fiig:	
A110	al